

Substitute Form PTO-1449
(Modified)U.S. Department of Commerce
Patent and Trademark OfficeAttorney's Docket No.
07977-226002Application No.
09,596,755**Information Disclosure Statement
by Applicant**

(Use several sheets if necessary)

(37 CFR § 1.98(b))

Applicant
Hisashi OhtaniFiling Date
June 15, 2000Group Art Unit
1765**U.S. Patent Documents**

Examiner Initial	Desig. ID	Patent Number	Issue Date	Patentee	Class	Subclass	Filing Date If Appropriate
/	AA	5 771 110	Jun 23, 1998	Hirano et al.			
/	AB	5 837 568	Nov 17, 1998	Yoneda et al.			
	AC						
	AD						
	AE						
	AF						
	AG						
	AH						

Foreign Patent Documents or Published Foreign Patent Applications

Examiner Initial	Desig. ID	Document Number	Publication Date	Country or Patent Office	Class	Subclass	Translation	
							Yes	No
/	AI	9-51099	2/18/97	Japan			ABS	
/	AJ	9-51100	2/18/97	Japan			ABS	
/	AK	9-74201 ✓	3/18/97	Japan			ABS	
/	AL	9-107108 ✓	4/22/97	Japan			ABS	
/	AM	9-237900 ✓	9/9/97	Japan			ABS	
/	AN	10-294469 ✓	11/4/98	Japan			ABS	
/	AO	2000-82822 ✓	3/21/00	Japan			ABS	
/	AP	2000-82821	3/21/00	Japan			ABS	

Other Documents (include Author, Title, Date, and Place of Publication)

Examiner Initial	Desig. ID	Document
/	AQ	Hatalis et al., "Solid phase crystallization of amorphous silicon by rapid thermal processing for flat panel display applications." Electrochemical Society Proceedings Volume 98-22, pp 92-99.
	AR	
	AS	

Examiner Signature

Date of Submission

EXAMINER: Initials citation considered. Draw line through citation if not in conformance and not considered. Include copy of this form with examination report.